

# DATA SHEET

**ELECTROSTATIC DISCHARGE  
PROTECTION DEVICES**

**INDUSTRIAL / CONSUMER**

SAT36A05L05

RoHS compliant & Halogen free



Product specification— March 20, 2021 V.2



## Electrostatic Discharged Protection Devices (ESD) Data Sheet

### Description

Brightking's SAT36A05L05 is designed to protect sensitive electronics from damage or latch-up due to ESD and other voltage induced transient events. It is designed for use in applications where board space is at a premium. Each device will protect up to five lines. It is unidirectional devices and may be used on lines where the signal polarities are above ground. The low profile SOT-363 package allows flexibility in the design of crowded circuit boards.

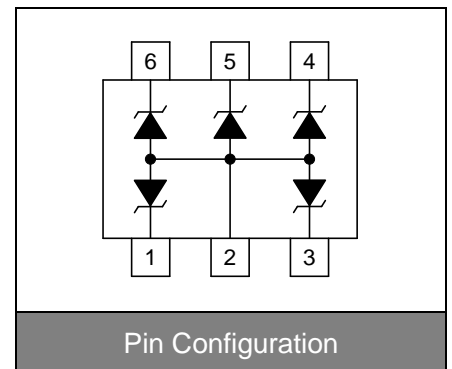


**Contact : ±8kV**  
**Air : ±15kV**



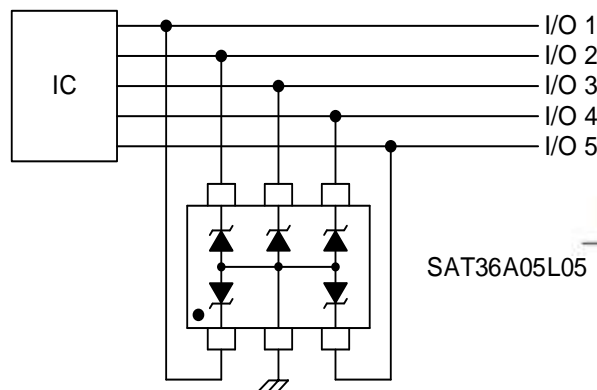
### Features

- IEC61000-4-2 ESD 15KV Air, 8KV contact compliance
- SOT-363 surface mount package
- Protects five unidirectional lines
- Peak power dissipation of 100W under 8/20µs waveform
- Working voltage: 5V
- Low leakage current
- Low operating and clamping voltages
- Solid-state silicon avalanche technology
- Lead Free/RoHS compliant
- Solder reflow temperature: Pure Tin-Sn, 260~270°C
- Flammability rating UL 94V-0
- Meets MSL level 1, per J-STD-020
- Marking: WF or 05C



### Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Portable instrumentation
- Set Top Box (STB)
- Servers, notebook and desktop PC
- Digital cameras



## Maximum Ratings

Rating	Symbol	Value	Unit
Peak pulse power (tp=8/20μs waveform)	P <sub>PP</sub>	100	W
ESD voltage (Contact discharge)	V <sub>ESD</sub>	±8	kV
ESD voltage (Air discharge)		±15	
Storage & operating temperature range	T <sub>STG</sub> , T <sub>J</sub>	-55~+150	°C

## Electrical Characteristics (T<sub>J</sub>=25°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Reverse stand-off voltage	V <sub>RWM</sub>				5	V
Reverse breakdown voltage	V <sub>BR</sub>	I <sub>BR</sub> =1mA	6			V
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> =5V Each I/O pin			5	μA
Clamping voltage (tp=8/20μs)	V <sub>C</sub>	I <sub>PP</sub> =1A			9.8	V
Peak Pulse Current(tp=8/20μs)	I <sub>PP</sub>				5	A
Off state junction capacitance	C <sub>J</sub>	0Vdc, f=1MHz Between I/O pins and GND			50	pF

### Typical Characteristics Curves

Figure 1. Power Derating Curve

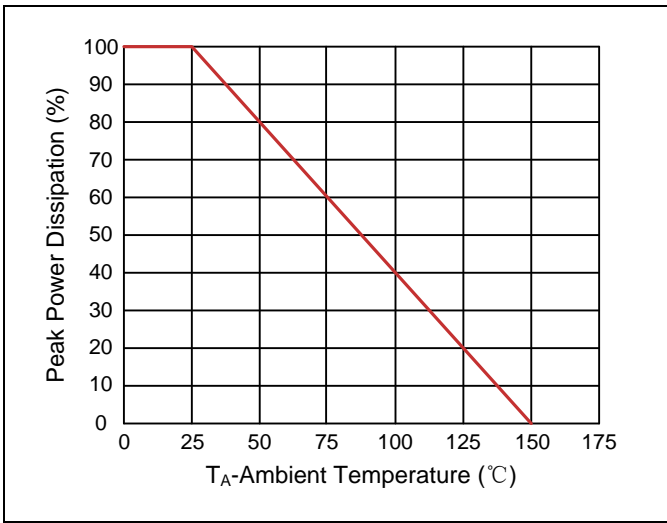


Figure 2. Pulse Waveforms

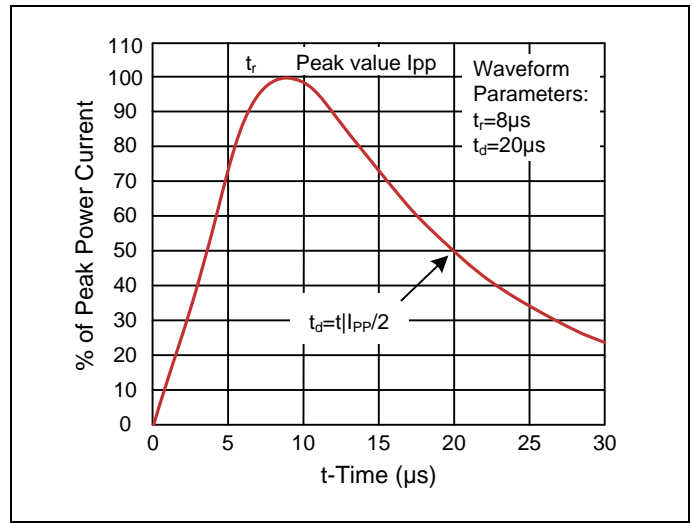


Figure 3. Non-Repetitive Peak Pulse vs. Pulse Time

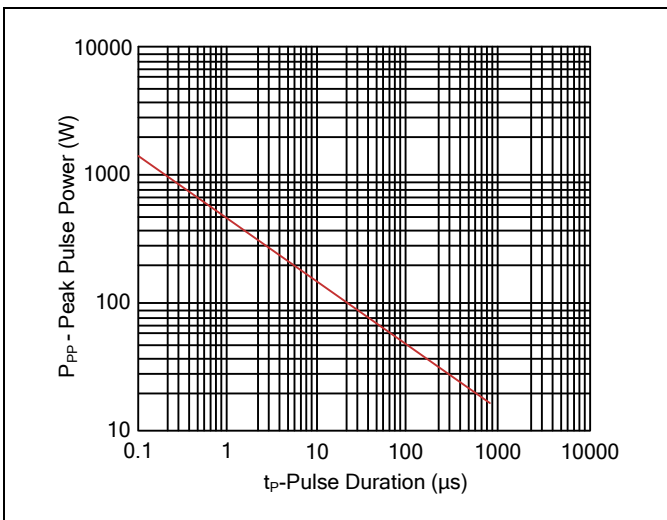
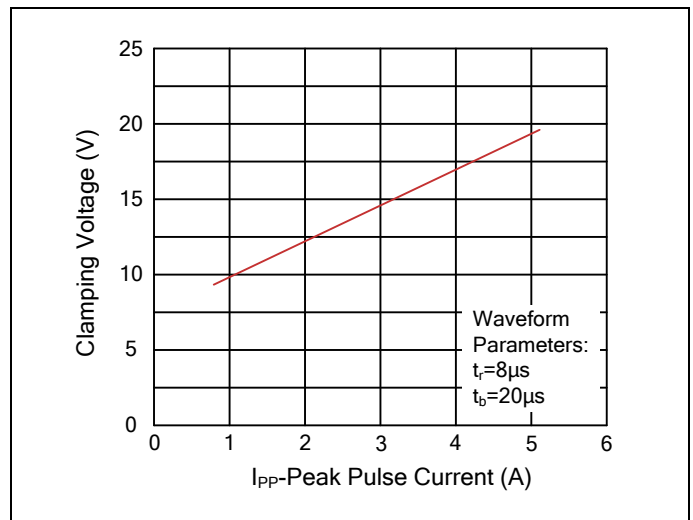
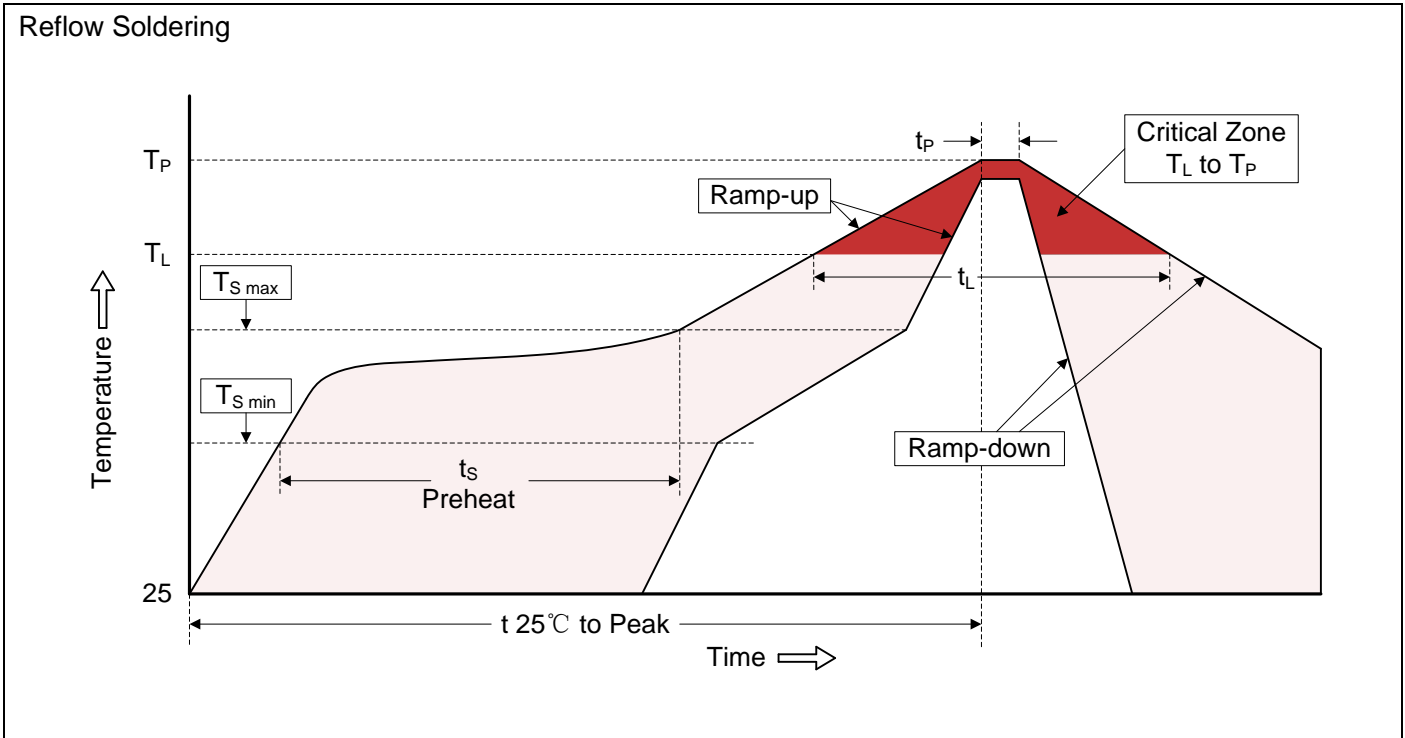


Figure 4. Clamping Voltage vs. Peak Pulse Current



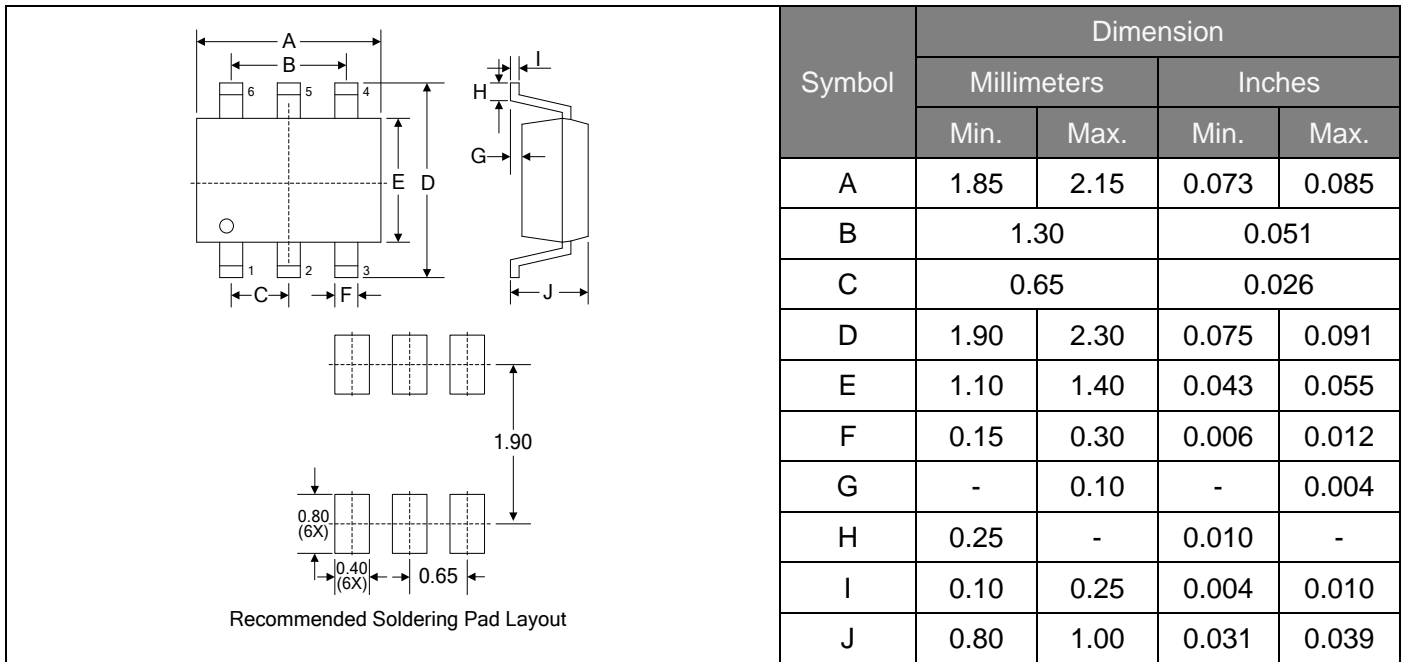
### Recommended Soldering Conditions



#### Recommended Conditions

Profile Feature	Pb-Free Assembly
Average ramp-up rate ( $T_L$ to $T_P$ )	3°C/second max.
Preheat -Temperature Min ( $T_{S\ min}$ ) -Temperature Max ( $T_{S\ max}$ ) -Time (min to max) ( $t_s$ )	150°C 200°C 60-180 seconds
$T_{S\ max}$ to $T_L$ -Ramp-up Rate	3°C/second max.
Time maintained above: -Temperature ( $T_L$ ) -Time ( $t_L$ )	217°C 60-150 seconds
Peak Temperature ( $T_P$ )	260°C
Time within 5°C of actual Peak Temperature ( $t_p$ )	20-40 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

**Dimensions (SOT-363)**



**Packaging**

